UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.usplo.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO. CONFIRMATION N		
10/050,195	01/16/2002	Sang-Bom Kang	5649-912 6301		
20792 MYFRS RIGE	7590 09/25/2007 EL SIBLEY & SAJOVEC	- EXAMINER			
PO BOX 37428			IM, JUNGHWA M		
RALEIGH, NC 27627			ART UNIT	PAPER NUMBER	
			2811		
			MAIL DATE	DELIVERY MODE	
			09/25/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

					[/
		Application No		Applicant(s)	3
Office Action Summary		10/050,195		KANG ET AL.	
		Examiner		Art Unit	<del> </del>
		Junghwa M. Im		2811	
Period fo	The MAILING DATE of this communication app or Reply	pears on the cove	r sheet with the co	orrespondence addre	ess
VV HIC - Exte after - If NC - Failt Any	ORTENED STATUTORY PERIOD FOR REPLICATION OF THE MAILING DISTRIBUTION OF THE MAILING DI	ATE OF THIS CO 36(a). In no event, how will apply and will expire	OMMUNICATION vever, may a reply be time s SIX (6) MONTHS from to	l. ely filed he mailing date of this comr	
Status					
2a)⊠	Responsive to communication(s) filed on <u>22 July</u> This action is <b>FINAL</b> . 2b) This Since this application is in condition for alloware closed in accordance with the practice under E	action is non-fin	rmal matters, pro	secution as to the m 3 O.G. 213.	nerits is
Disposit	ion of Claims				
5) 🗌 6) 🔲 7) 🔲	Claim(s) 1,3-7,13,14 and 25-31 is/are pending 4a) Of the above claim(s) is/are withdray Claim(s) is/are allowed. Claim(s) 1,3-7,13,14 and 25-31 is/are rejected Claim(s) is/are objected to. Claim(s) are subject to restriction and/o	wn from conside	ration.		
Applicat	ion Papers				
10)🖂	The specification is objected to by the Examine The drawing(s) filed on 16 January 2002 is/are Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Ex	: a)⊠ accepted drawing(s) be held tion is required if th	in abeyance. See ne drawing(s) is obje	37 CFR 1.85(a). ected to. See 37 CFR	1.121(d).
Priority (	under 35 U.S.C. § 119		. ,		
a)	Acknowledgment is made of a claim for foreign All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureau See the attached detailed Office action for a list	s have been rece s have been rece rity documents h u (PCT Rule 17.2	eived. eived in Application ave been received 2(a)).	on No d in this National Sta	age
2) 🔲 Notic 3) 🔲 Infor	te of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08)		Paper No(s)/Mail Dat Notice of Informal Pa	PTO-413) ie itent Application (PTO-15	52)
Раре	r No(s)/Mail Date	6) 🗔	Other:		

Art Unit: 2811

## **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1, 3-7, 13, 25-29 and 30 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chang et al. (US 5,672,543), hereinafter Chang in view of Taguwa et al. (US 6,107,190), hereinafter Taguwa and Moise et al. (US 6,534,809), hereinafter Moise.

Regarding claims 1 and 25, Fig.1 of Chang shows a contact plug in an insulating layer 20 having tensile stress (col. 1, lines 53-54), a TiN layer 26 surrounding the plug on contact and having compressive stress (col. 1, lines 32-33) and an ohmic layer 24 between the insulating layer and the TiN layer.

Chang discloses substantially the entire claimed device except a TiN plug. Taguwa teaches a TiN plug having a tensile stress (col. 2, lines 33-39) in lieu of W plug of Chang. It would have been obvious to one of ordinary skill in the art at the time of the invention to form a TiN plug in the device of Chang with Taguwa's teaching in order to reduced a production cost as taught in column 1, lines 57-61 of Taguwa.

The device with the teachings of Chang and Taguwa fails to show that a lower electrode of the capacitor structure contacting the upper surface of the TiN plug. Fig.1 of Moise shows a bottom electrode 124 of a capacitor 125 formed on a TiN contact plug 114 and a TiN liner layer (col. 7, lines 43-50).

Art Unit: 2811

It would have been obvious to one of ordinary skill in the art at the time of the invention to incorporate Moise's teaching to the device of Chang and Taguwa in order to fabricate a DRAM array with a charge storage capacitor.

Regarding claim 3, the liner of Chang inherently possesses an amorphous structure since it is deposited by CVD.

Regarding claims 4-5, Fig. 1 of Chang shows an ohmic layer, Ti 24 between the liner and the insulating layer.

Regarding claim 6, the combination of Chang/Taguwa/Mori does not explicitly disclose the thickness of the ohmic layer as claimed. However, it would have been obvious to one of ordinary skill in the art at the time of the invention to have the recited range of the thickness for an ohmic layer to improve the conductivity, since it would have been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only in routine skill in the art. *In re Aller*, 105 USPQ 233.

Regarding claim 7, the combination of Chang/Taguwa/Mori does not explicitly show the thickness of the liner layer as claimed. However, it would have been obvious to one of ordinary skill in the art at the time of the invention to have the recited range of the thickness for an liner layer to enhance the adherence, since it would have been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only in routine skill in the art. *In re Aller*, 105 USPQ 233.

Regarding claim 13, Fig.1 of Moise shows a capacitor 125 formed on a contact plug 114 and a capacitor with a lower electrode 124 made of Pt (col. 9, lines 27-39).

Regarding claim 26, Taguwa discloses a TiN plug formed by CVD (col.1, lines 57-61).

Art Unit: 2811

Regarding claim 27, Chang discloses a TiN layer formed by CVD (col. 3, lines 13-14). In addition, CVD, ALD, CVD AND ALD are a process designation and would thus not carry patentable weight in this claim drawn to a product. See *In re Thorp*, 227 USPQ 964 (Fed. Cir. 1985).

Regarding claim 28, Chang discloses a TiN layer has an amorphous crystal structure since it is deposited by PVC.

Regarding claim 29, Chang discloses a TiN liner formed by physical vapor deposition (col. 3, line 13). In addition, IPVD is a process designation and would thus not carry patentable weight in this claim drawn to a product. See *In re Thorp*, 227 USPQ 964 (Fed. Cir. 1985).

Regarding claim 31, Moise shows the upper conductive layer made of Pt (col.9, lines 30-33).

Regarding claim 32, Moise shows the upper conductive layer (51) comprising a lower electrode of a capacitor (col. 9, lines 27-29).

Claims 14 and 30 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chang in view of Mori and Taguwa applied to claims 1 and 25 further in view of Nagasaka et al. (US 6,300,683), hereinafter Nagasaka.

Regarding claims 14 and 30, the combination of Chang/Mori/Taguwa discloses most aspects of the instant invention except a shape of the contact plug. However, Fig. 19D of Nagasaka shows a tapered contact plug 12.

It would have been obvious to one of ordinary skill in the art at the time of the invention to form a tapered contact plug of Chang/Mori/Taguwa with Nagasaka's teaching in order to form

Art Unit: 2811

the plug without cracks. It is well known in the art that it is easier to fill contact/plug openings with tapered sidewalls.

## Response to Arguments

Applicant's arguments filed June 22, 2007 have been fully considered but they are not persuasive.

Applicants argue that the combination of Chang/Mori/Taguwa would not show the limitations recited in claims 1 and 25. In particular, Applicants argue that "[t]he Moise reference fails to provide the teachings missing from Chang and Taguwa. As shown in FIG. 1 and described at col. 9, lines 27 - 30, Moise discloses a capacitor 125 that may be formed on a plug 114 or a barrier layer 122. Moise does not include any disclosure or suggestion of forming a capacitor that has a lower electrode that contacts both an upper surface of a TiN contact plug and an upper surface of a TiN liner." This is not persuasive. Fig. 1 of Moise shows a lower electrode 124 of a capacitor 125 formed on an upper surface of the plug 114 and a liner/barrier layer 116, and the combination of Chang/Taguwa shows a TiN contact plug with tensile and a TiN liner having compressive stress. Therefore, the combination of Chang/Mori/Taguwa would show all the limitations recited in claim 1 and 25.

Applicants further argue that "Applicants further submit that there would be no motivation for combining the teachings from these three different references. .... It appears, therefore, that the Office Action gains its alleged impetus or suggestion to combine the cited references by hindsight reasoning informed by Appellants' disclosure, which is an inappropriate basis for combining references." However, there is no requirement that a motivation to make the

Art Unit: 2811

modification be expressly articulated. The test for combining references is what the combination of disclosures taken as a whole would suggest to one of ordinary skill in the art. *In re McLaughlin*, 170 USPQ 209 (CCPA1971). References are evaluated by what they suggest to one versed in the art, rather than by their specific disclosures. *In re Bozek*, 163 USPQ 595 (CCPA) 1969. In addition, applicant's argument of "hindsight reasoning informed by Appellants' disclosure" is merely speculative without substantiation.

## Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Junghwa M. Im whose telephone number is (571) 272-1655. The examiner can normally be reached on MON.-FRI. 8:30AM-5:00PM.

Art Unit: 2811

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Lynne A. Gurley can be reached on (571) 272-1670. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Junghwa M. Im

Examiner

Art Unit 2811

jmi 9/9/2007